

900V N-Channel QFET; Package: TO-263(D2PAK); No of Pins: 2; Container: Tape & Reel, MOSFET 900V N-Channel QFET

Manufacturers	<u>ON Semiconductor, LLC</u>
Package/Case	TO-263
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FQB5N90TM or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

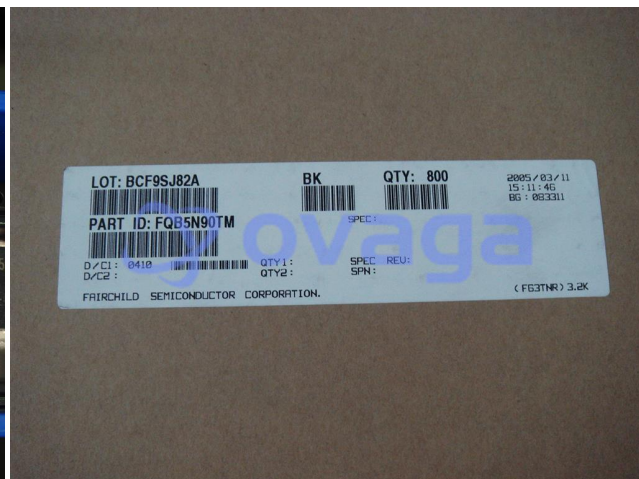


General Description

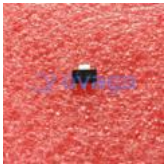
This N-Channel enhancement mode power MOSFET is produced using a proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Application

ONSEMI



Related Products



[FQT7N10LTF](#)

ON Semiconductor, LLC
SOT-223



[FQPF13N50CF](#)

ON Semiconductor, LLC
TO-220F



[FQD19N10LTM](#)

ON Semiconductor, LLC
TO-252



[FQD12N20LTM](#)

ON Semiconductor, LLC
TO-252



[FQA140N10](#)

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TO-3P



[FQPF70N10](#)

ON Semiconductor, LLC
TO-220F



[FQP17P10](#)

ON Semiconductor, LLC
TO-220



[FQB27P06TM](#)

ON Semiconductor, LLC
TO-263